

Figure 2. QFN-16 Pinout (Top View)

Table 1. PIN DESCRIPTION

Pin	Name	I/O	Description
1	V _{TCLK}	_	Internal 50 Ω Termination Pin for $\overline{\text{CLK}}$.
2	CLK	LVPECL, CML, LVCMOS, LVTTL, LVDS	Inverted Differential Clock/Data Input. (Note 1)
3	CLK	LVPECL, CML, LVCMOS, LVTTL, LVDS	Non-inverted Differential Clock/Data Input. (Note 1)
4	V _{TCLK}	-	Internal 50 Ω Termination Pin for CLK.
5,16	V _{EE}	Power Supply	Negative Supply Voltage. All V_{EE} pins must be externally connected to a Power Supply to guarantee proper operation.
6	Q3	CML Output	Inverted Differential Output 3 with Internal 50 Ω Source Termination Resistor. (Note 2)
7	Q3	CML Output	Non-inverted Differential Output 3 with Internal 50 Ω Source Termination Resistor. (Note 2)
8,13	V _{CC}	Power Supply	Positive Supply Voltage. All $V_{\rm CC}$ pins must be externally connected to a Power Supply to guarantee proper operation.
9	Q2	CML Output	Inverted Differential Output 2 with Internal 50 Ω Source Termination Resistor. (Note 2)
10	Q2	CML Output	Non-inverted Differential Output 2 with Internal 50 Ω Source Termination Resistor. (Note 2)
11	Q1	CML Output	Inverted Differential Output 1 with Internal 50 Ω Source Termination Resistor. (Note 2)
12	Q1	CML Output	Non-inverted Differential Output 1 with Internal 50 Ω Source Termination Resistor. (Note 2)
14	Q0	CML Output	Inverted Differential Output 0 with Internal 50 Ω Source Termination Resistor. (Note 2)
15	Q0	CML Output	Non-inverted Differential Output 0 with Internal 50 Ω Source Termination Resistor. (Note 2)
-	EP	-	Exposed Pad. Thermal pad on the package bottom must be attached to a heatsinking conduit to improve heat transfer. It is recommended to connect the EP to the lower potential (V_{EE}).

In the differential configuration when the input termination pins (V_{TCLK}, V_{TCLK}) are connected to a common termination voltage or left open, and if no signal is applied on CLK and CLK, then the device will be susceptible to self–oscillation.
 CML outputs require 50 Ω receiver termination resistors to V_{CC} for proper operation.

Table 2. ATTRIBUTES

Character	Value					
ESD Protection Human Body Model Machine Model Charged Device Model		> 1500 V > 50 V > 500 V				
Moisture Sensitivity (Note 3)	Pb Pkg	Pb-Free Pkg				
	QFN-16	Level 1	Level 1			
Flammability Rating	UL 94 V-0	@ 0.125 in				
Transistor Count	38	37				
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test						

^{3.} For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	Positive Power Supply	V _{EE} = 0 V		3.6	V
VI	Input Voltage	V _{EE} = 0 V	$V_{EE} \le V_I \le V_{CC}$	3.6	V
V _{INPP}	Differential Input Voltage CLK - CLK	$\begin{array}{c} V_{CC} - V_{EE} \geq 2.8 \ V \\ V_{CC} - V_{EE} < 2.8 \ V \end{array}$		2.8 V _{CC} – V _{EE}	V V
I _{IN}	Input Current Through R_T (50 Ω Resistor)	Static Surge		45 80	mA mA
l _{out}	Output Current	Continuous Surge		25 50	mA mA
T _A	Operating Temperature Range	QFN-16		-40 to +85	°C
T _{stg}	Storage Temperature Range			−65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient) (Note 4)	0 lfpm 500 lfpm	QFN-16 QFN-16	42 36	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	2S2P (Note 4)	QFN-16	3 to 4	°C/W
T _{sol}	Wave Solder Pb Pb-Free			265 265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

4. JEDEC standard multilayer board – 2S2P (2 signal, 2 power).

Table 4. DC CHARACTERISTICS, CLOCK Inputs, CML Outputs (V_{CC} = 2.375 V to 3.465 V, V_{EE} = 0 V, T_A = -40°C to +85°C) (Note 5)

Symbol	Characteristic	Min	Тур	Max	Unit
I _{CC}	Power Supply Current (Inputs and Outputs Open)		140	190	mA
V _{OH}	Output HIGH Voltage (Note 6)	V _{CC} - 60	V _{CC} – 20	V _{CC}	mV
V _{OL}	Output LOW Voltage (Note 6)	V _{CC} – 530	V _{CC} - 420	V _{CC} – 360	mV
Differential	Input Driven Single-Ended (see Figures 10 & 12) (Note 8)				
V _{th}	Input Threshold Reference Voltage Range (Note 7)	800		V _{CC} – 75	mV
V _{IH}	Single-ended Input HIGH Voltage	1200		V _{CC}	mV
V _{IL}	Single-ended Input LOW Voltage	V _{EE}		V _{CC} – 150	mV
V _{ISE}	Single-Ended Input Voltage (V _{IH} - V _{IL})	150		2500	mV
Differential	Inputs Driven Differentially (see Figures 11 & 13) (Note 9)				
V _{IHCLK}	Differential Input HIGH Voltage	1200		V _{CC}	mV
V _{ILCLK}	Differential Input LOW Voltage	V_{EE}		V _{CC} – 75	mV
V _{CMR}	Input Common Mode Range (Differential Configuration) (Note 10)	800		V _{CC} – 38	mV
V _{ID}	Differential Input Voltage (V _{IHCLK} - V _{ILCLK})	75		2500	mV
I _{IH}	Input HIGH Current CLK / CLK (V _{TCLK} /V _{TCLK} Open)	0	25	100	μΑ
I _{IL}	Input LOW Current CLK / CLK (V _{TCLK} /V _{TCLK} Open)	-10	0	10	μΑ
R _{TIN}	Internal Input Termination Resistor	45	50	55	Ω
R _{TOUT}	Internal Output Termination Resistor	45	50	55	Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

6.38

 $m\Omega/^{\circ}C$

5. Input and output parameters vary 1:1 with $V_{\mbox{\footnotesize CC}}$.

 $R_{Temp\ Coef}$

6. CML outputs require 50 Ω receiver termination resistors to V_{CC} for proper operation.

Internal I/O Termination Resistor Temperature Coefficient

V_{th} is applied to the complementary input when operating in single-ended mode. V_{th} = (V_{IH} - V_{IL})/2.
 Vth, V_{IH}, V_{IL}, and V_{ISE} parameters must be complied with simultaneously.
 V_{IHD}, V_{ILD}, V_{ID} and V_{CMR} parameters must be complied with simultaneously.
 V_{CMR} min varies 1:1 with V_{EE}, V_{CMR} max varies 1:1 with V_{CC}. The V_{CMR} range is referenced to the most positive side of the differential input size.

Table 5. AC CHARACTERISTICS ($V_{CC} = 2.375 \text{ V to } 3.465 \text{ V}, V_{EE} = 0 \text{ V}$; Note 11)

		-40°C		25°C		85°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V _{OUTPP}	Output Voltage Amplitude (@V _{INPPmin}) $f_{in} \le 6 \text{ GHz}$ (See Figure 4) $f_{in} \le 8 \text{ GHz}$	280 125	400 300		280 125	400 300		280 125	400 300		mV
f _{data}	Maximum Operating Data Rate	10	12		10	12		10	12		Gb/s
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential	70	110	150	70	110	150	70	110	150	ps
t _{SKEW}	Duty Cycle Skew (Note 12) Within-Device Skew Device-to-Device Skew (Note 13)		2.0 6.0 20	5.0 15 50		2.0 6.0 20	5.0 15 50		2.0 6.0 20	5.0 15 50	ps
UITTER	RMS Random Clock Jitter (Note 14) $f_{in} = 6 \text{ GHz}$ $f_{in} = 8 \text{ GHz}$ Peak/Peak Data Dependent Jitter $f_{in} = 2.488 \text{ Gb/s}$ (Note 15) $f_{data} = 5 \text{ Gb/s}$ $f_{data} = 10 \text{ Gb/s}$		0.2 0.2 2.0 5.0 6.0	0.5 0.5 5.0 8.0 10		0.2 0.2 2.0 5.0 6.0	0.5 0.5 5.0 8.0 10		0.2 0.2 2.0 5.0 6.0	0.5 0.5 5.0 8.0 10	ps
V _{INPP}	Input Voltage Swing/Sensitivity (Differential Configuration) (Note 16)	75	400	2500	75	400	2500	75	400	2500	mV
t _r t _f	Output Rise/Fall Times @ 1 GHz Q, Q (20% – 80%)		30	60		30	60		30	60	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 11. Measured by forcing V_{INPP} (TYP) from a 50% duty cycle clock source. All loading with an external R_L = 50 Ω to V_{CC} . Input edge rates 40 ps (20% 80%).
- 12. Duty cycle skew is measured between differential outputs using the deviations of the sum of Tpw- and Tpw+ @1 GHz.
- 13. Device to device skew is measured between outputs under identical transition @ 1 GHz.
- 14. Additive RMS jitter with 50% duty cycle clock signal at 10 GHz.
- 15. Additive peak-to-peak data dependent jitter with input NRZ data at PRBS $2^{^23}$ -1.
- $16.V_{INPP}$ (MAX) cannot exceed $V_{CC} V_{EE}$. Input voltage swing is a single-ended measurement operating in differential mode.

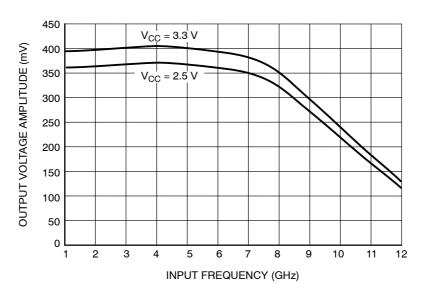


Figure 3. Output Voltage Amplitude (V_{OUTPP}) versus Input Clock Frequency (f_{in}) at Ambient Temperature (Typical) ($V_{INPP} = 400 \text{ mV}$)

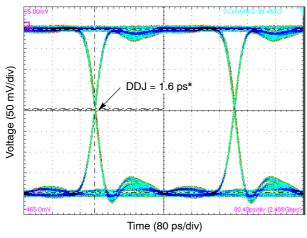


Figure 4. Typical Output Waveform at 2.488 Gb/s with PRBS 2^{23} -1 (V_{inpp} = 75 mV)

*Input signal DDJ = 6.4 ps

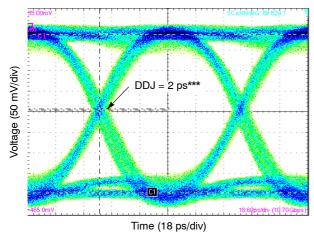


Figure 6. Typical Output Waveform at 10.7 Gb/s with PRBS 2^{23} -1 (V_{inpp} = 75 mV)

***Input signal DDJ = 11 ps

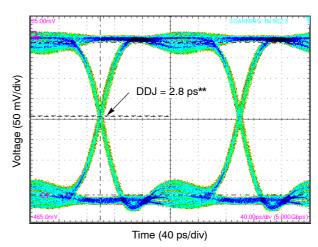


Figure 5. Typical Output Waveform at 5 Gb/s with PRBS 2²³-1 (V_{inpp} = 75 mV)

**Input signal DDJ = 7.2 ps

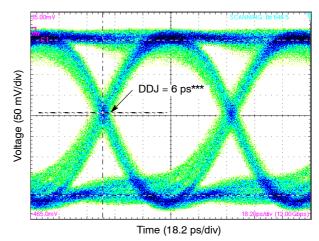


Figure 7. Typical Output Waveform at 12 Gb/s with PRBS 2^{23} -1 (V_{inpp} = 75 mV)

***Input signal DDJ = 13 ps

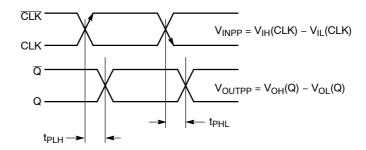


Figure 8. AC Reference Measurement

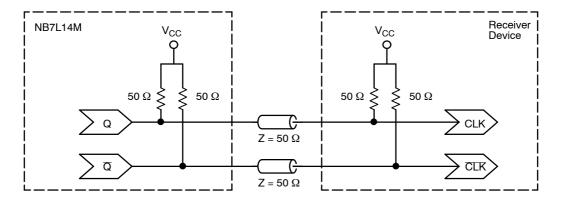


Figure 9. Typical Termination for 16 mA Output Driver and Device Evaluation (Refer to Application Notes AND8020/D and AND8173/D)

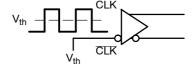


Figure 10. Differential Input Driven Single-Ended

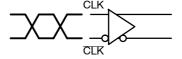


Figure 11. Differential Inputs Driven Differentially

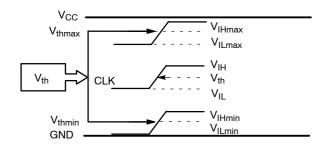


Figure 12. V_{th} Diagram

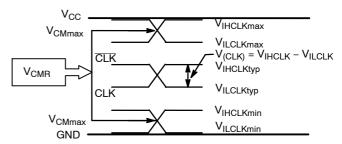


Figure 13. V_{CMR} Diagram

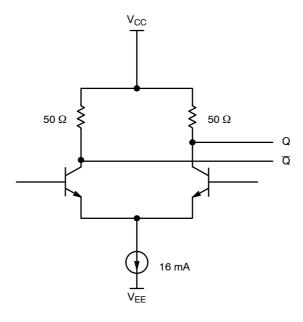


Figure 14. CML Output Structure

Table 6. INTERFACING OPTIONS

INTERFACING OPTIONS	CONNECTIONS		
CML	Connect V_{TCLK} and $\overline{V_{TCLK}}$ to V_{CC}		
LVDS	Connect V_{TCLK} , $\overline{V_{TCLK}}$ Together for CLK Input		
AC-COUPLED	Bias V_{TCLK} , $\overline{V_{TCLK}}$ Inputs within (VCMR) Common Mode Range		
RSECL, LVPECL	Standard ECL Termination Techniques. See AND8020/D.		
LVTTL, LVCMOS	An external voltage should be applied to the unused complementary differential input. Nominal voltage is 1.5 V for LVTTL and $V_{\rm CC}/2$ for LVCMOS inputs.		

Application Information

All NB7L14M inputs can accept PECL, CML, LVTTL, LVCMOS and LVDS signal levels. The limitations for differential input signal (LVDS, PECL, or CML) are

minimum input swing of 75 mV and the maximum input swing of 2500 mV. Within these conditions, the input voltage can range from $V_{\rm CC}$ to 1.2 V. Examples interfaces are illustrated below in a 50 Ω environment (Z = 50 Ω).

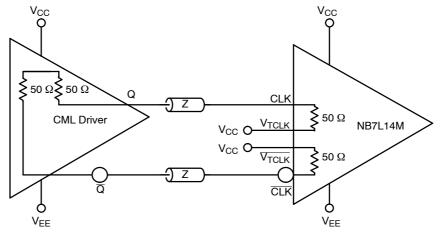


Figure 15. CML to CML Interface

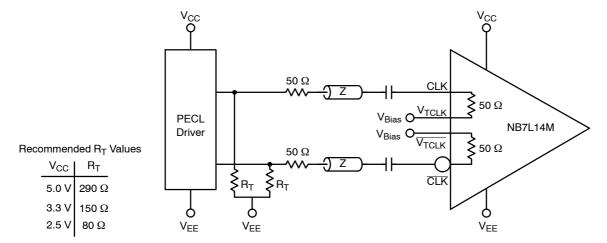


Figure 16. PECL to CML Receiver Interface

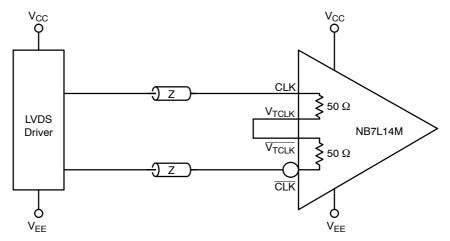


Figure 17. LVDS to CML Receiver Interface

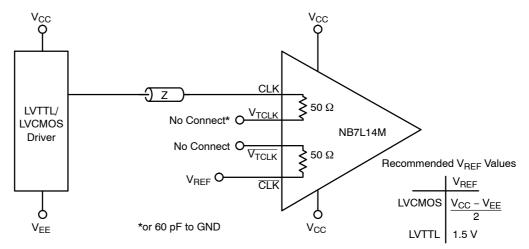


Figure 18. LVCMOS/LVTTL to CML Receiver Interface

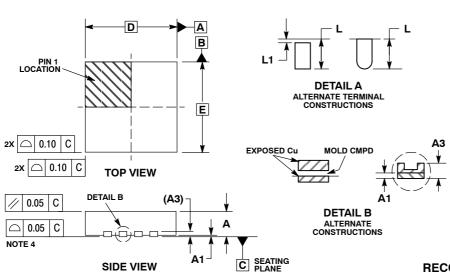
ORDERING INFORMATION

Device	Package	Shipping [†]
NB7L14MMNG	QFN-16 (Pb-Free)	123 Units/Rail
NB7L14MMNR2G	QFN-16 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

QFN16 3x3, 0.5P CASE 485G ISSUE F



⊕ 0.10 | C | A | B

E2

0.10

0.05 C NOTE 3

C

AB

16X b

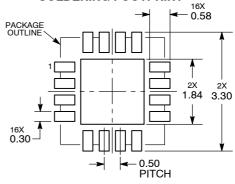
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NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
- 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS				
DIM	MIN	NOM	MAX		
Α	0.80	0.90	1.00		
A1	0.00	0.03	0.05		
А3	C).20 REF			
b	0.18	0.24	0.30		
D	3.00 BSC				
D2	1.65	1.75	1.85		
E	3	.00 BSC)		
E2	1.65	1.75	1.85		
е	0.50 BSC				
K	0.18 TYP				
L	0.30	0.40	0.50		
L1	0.00	0.08	0.15		

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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